	Hits	Search Text	DBs
1	1	ying$1oing near xu	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
2	113750	(mosfet or (bipolar near transistor$1))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
3	19	high near input near resist$4 near transistor$1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
4	830	high near input near2 transistor$1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
5	114368	1 or 2 or 4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
6	969941	(cut$4 near off) of cut$1off	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
7	3397	(improv$3 or facilitat$3 or assist$3 or help$3) near3 6	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
8	210	7 same transistor$1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
9	99	5 and 8	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
10	97624	negative near3 voltage$1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
11	8	9 and 10	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
12	93389	positive near2 voltage$1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
13	45701	10 same 12	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
14	13	8 and 13	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
15	41	heung$1yeung near shum	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB